

TC74ACT138P, TC74ACT138F, TC74ACT138FN, TC74ACT138FT**3 - TO - 8 LINE DECODER**

The TC74ACT138 is an advanced high speed CMOS 3 - to - 8 LINE DECODER fabricated with silicon gate and double - layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ($\bar{Y}0$ - $\bar{Y}7$) will go low.

When enable input G1 is held low or either $\bar{G}2A$ or $\bar{G}2B$ is held high, decoding function is inhibited and all outputs go high.

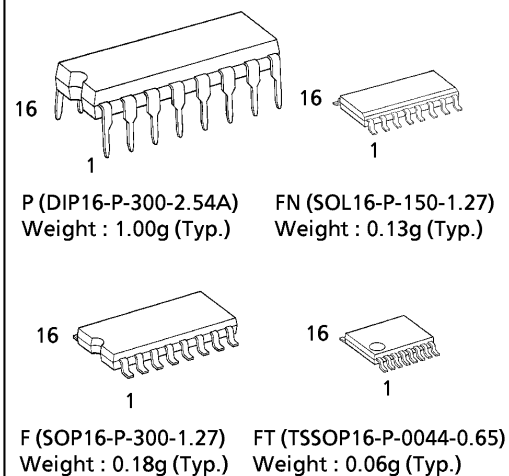
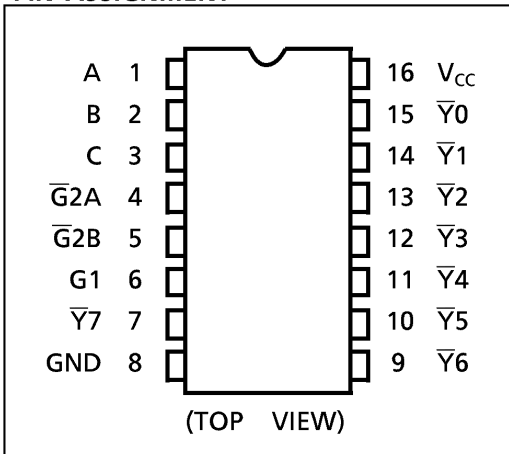
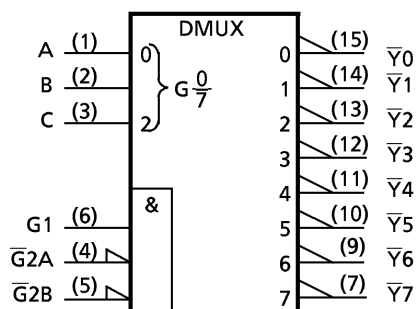
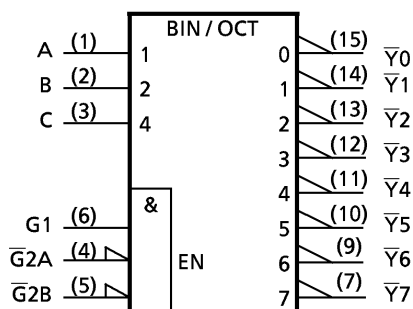
G1, $\bar{G}2A$, and $\bar{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed..... $t_{pd} = 6.0ns(\text{typ.})$ at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 8\mu A(\text{Max.})$ at $T_a = 25^\circ C$
- Compatible with TTL outputs ... $V_{IL} = 0.8V(\text{Max.})$
 $V_{IH} = 2.0V(\text{Min.})$
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 24mA(\text{Min.})$
 Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Pin and Function Compatible with 74F138

(Note) The JEDEC SOP (FN) is not available in Japan.

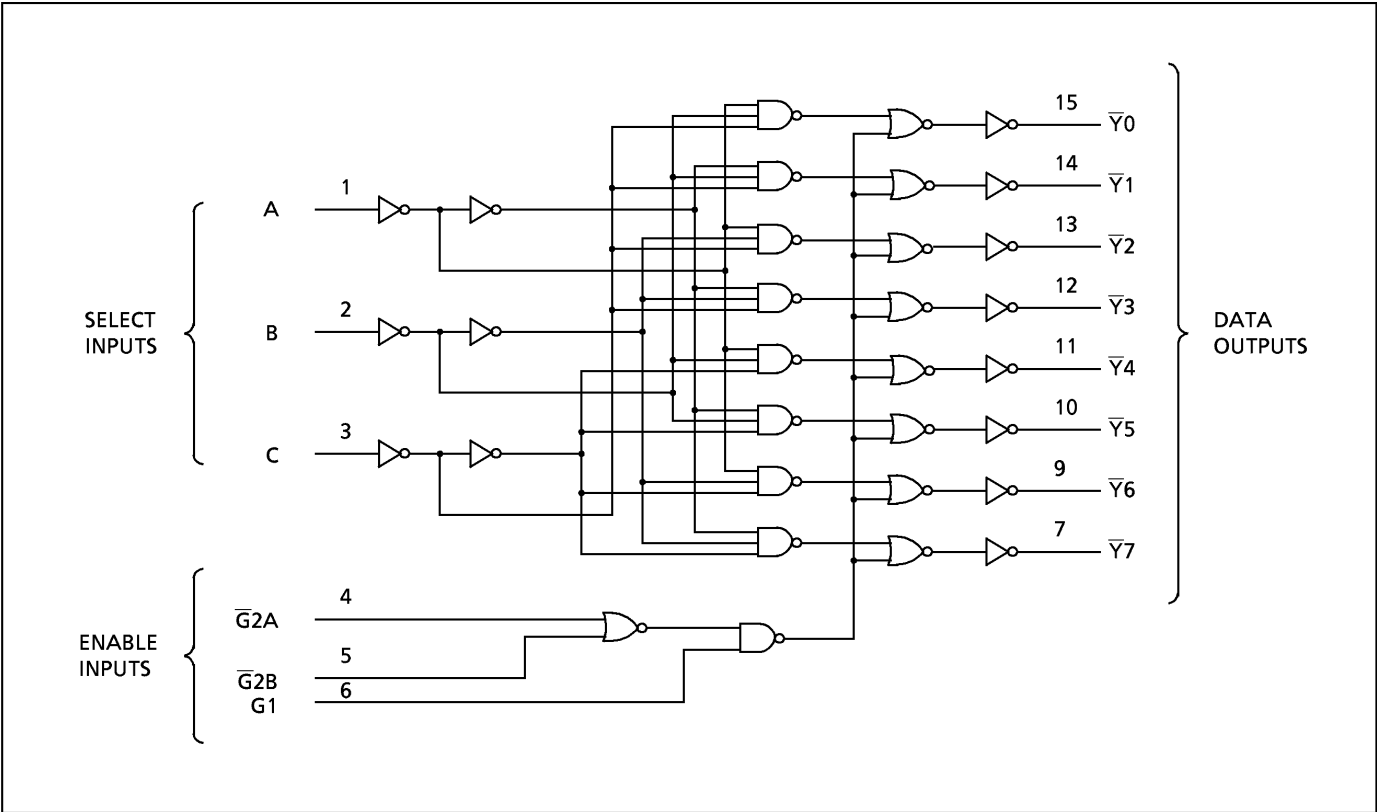
**PIN ASSIGNMENT****IEC LOGIC SYMBOL**

TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT			Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	
G1	G2A	G2B	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	H	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	X	H	X	X	X	H	H	H	H	H	H	H	H	NONE
H	L	L	L	L	L	L	H	H	H	H	H	H	H	Y0
H	L	L	L	L	H	H	L	H	H	H	H	H	H	Y1
H	L	L	L	H	L	H	H	L	H	H	H	H	H	Y2
H	L	L	L	H	H	H	H	H	L	H	H	H	H	Y3
H	L	L	H	L	L	H	H	H	H	L	H	H	H	Y4
H	L	L	H	L	H	H	H	H	H	H	L	H	H	Y5
H	L	L	H	H	L	H	H	H	H	H	H	L	H	Y6
H	L	L	H	H	H	H	H	H	H	H	H	H	L	Y7

X : Don't Care

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7.0$	V
DC Input Voltage	V_{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 50	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC} /Ground Current	I_{CC}	± 200	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP/TSSOP)	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	°C

*500mW in the range of $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	$4.5 \sim 5.5$	V
Input Voltage	V_{IN}	$0 \sim V_{CC}$	V
Output Voltage	V_{OUT}	$0 \sim V_{CC}$	V
Operating Temperature	T_{opr}	$-40 \sim 85$	°C
Input Rise and Fall Time	dt/dV	$0 \sim 10$	ns/V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \sim 85^\circ\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		$4.5 \begin{smallmatrix} \text{ } \\ \text{ } \end{smallmatrix} 5.5$	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}		$4.5 \begin{smallmatrix} \text{ } \\ \text{ } \end{smallmatrix} 5.5$	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50\mu\text{A}$	4.5	4.4	4.5	—	4.4	V
			$I_{OH} = -24\text{mA}$	4.5	3.94	—	—	3.80	
			$I_{OH} = -75\text{mA}^*$	5.5	—	—	—	3.85	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 50\mu\text{A}$	4.5	—	0.0	0.1	—	V
			$I_{OL} = 24\text{mA}$	4.5	—	—	—	0.44	
			$I_{OL} = 75\text{mA}^*$	5.5	—	—	—	1.65	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC} \text{ or } \text{GND}$	5.5	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC} \text{ or } \text{GND}$	5.5	—	—	8.0	—	80.0	
	I_C	PER INPUT : $V_{IN} = 3.4\text{V}$ OTHER INPUT : $V_{CC} \text{ or } \text{GND}$	5.5	—	—	1.35	—	1.5	mA

* : This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, $R_L = 500\Omega$, Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = − 40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (A, B, C − Y)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	6.7	10.1	1.0	11.5	ns
Propagation Delay Time (G1 − Y)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	6.8	10.5	1.0	12.0	
Propagation Delay Time (G2 − Y)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	6.9	11.0	1.0	12.5	
Input Capacitance	C _{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD} (1)			—	55	—	—	—	

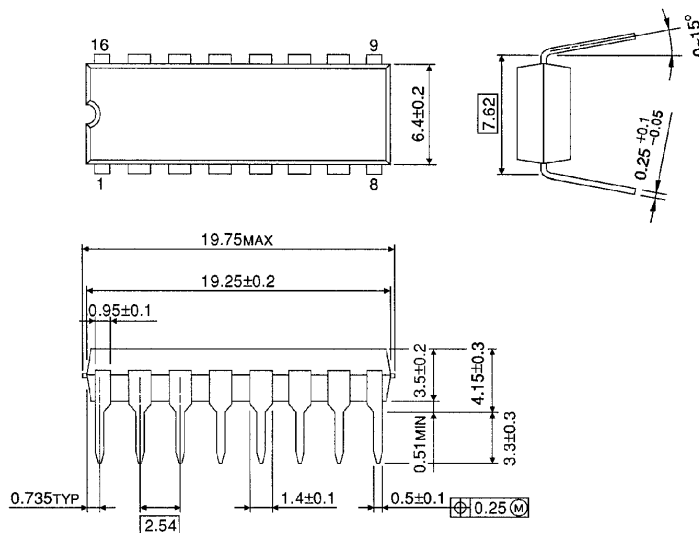
Note(1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{\text{CC(opr.)}} = C_{\text{PD}} \cdot V_{\text{CC}} \cdot f_{\text{IN}} + I_{\text{CC}}$$

DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

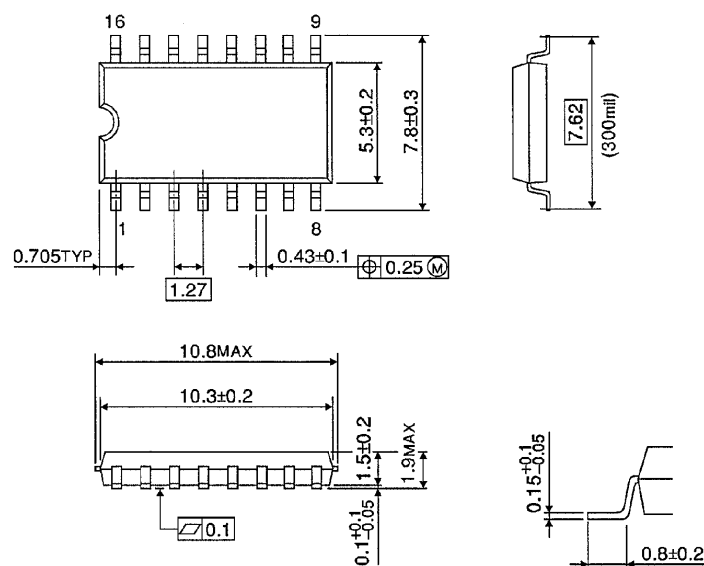
Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm

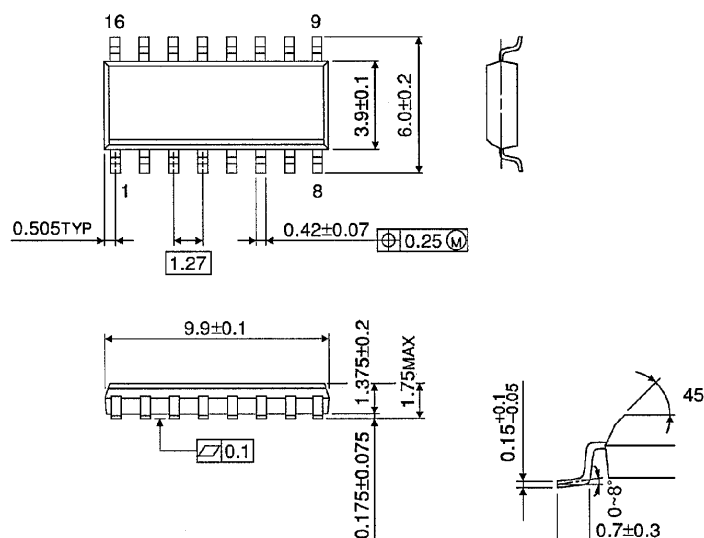


Weight : 0.18g (Typ.)

SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm

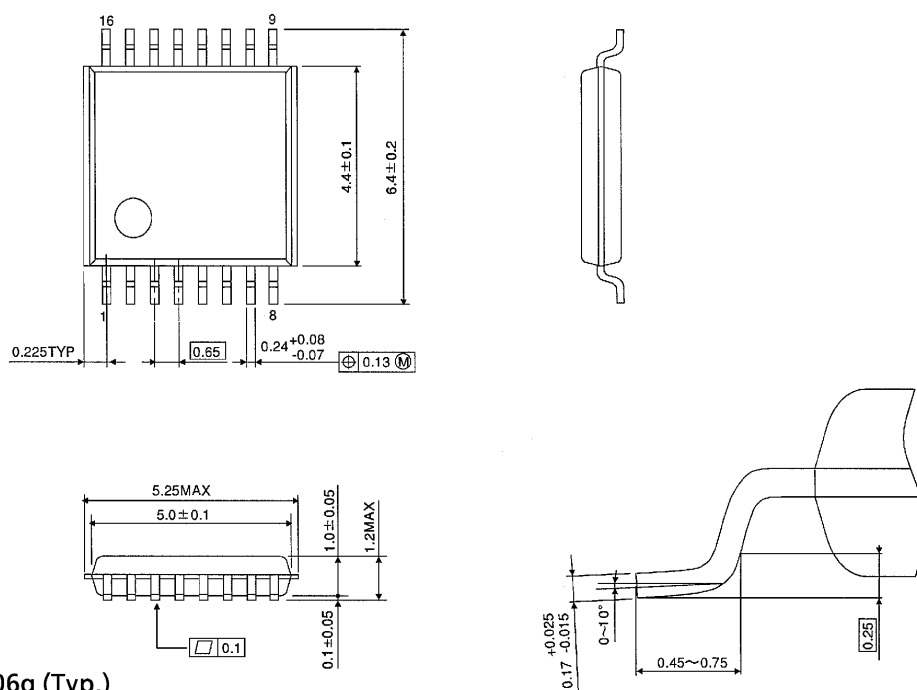
(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)

TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



Weight : 0.06g (Typ.)

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